



SVTR2800D Series

HIGH RELIABILITY HYBRID RADIATION TOLERANT DC-DC CONVERTERS

DESCRIPTION

The SVTR series of high reliability DC-DC converters is operable over the full military (-55 °C to +125 °C) temperature range with no power derating. Paramount to the SVTR series is a magnetic feedback circuit that is radiation immune. Operating at a nominal fixed frequency of 500 kHz, these regulated, isolated units utilize well controlled undervoltage lockout circuitry to eliminate slow start-up problems. The SVTR series has been characterized and tested for TID (Total Ionizing Dose) at HDR (High Dose Rate) and LDR (Low Dose Rate – ELDRS) per VPT's RHA plan. The SVTR series has also been characterized for SEE (Single Event Effects). VPT's certified radiation program per MIL-PRF-38534, Appendix G is currently under review by DSCC. Please contact DSCC at 614-692-0585 for details. This characterization and testing is performed at the critical semiconductor component piece-part level (RLAT) from traceable semiconductor lots as well as on the SVTR series hybrid converter level produced from the same traceable semiconductor lots evaluated during RLAT.

These converters are designed and manufactured in a facility qualified to ISO9001 and certified to MIL-PRF-38534 Class H and Class K and MIL-STD-883.

This product may incorporate one or more of the following U.S. patents:

5,784,266 5,790,389 5,963,438 5,999,433
 6,005,780 6,084,792 6,118,673

FEATURES

- High Reliability
- Very Low Output Noise
- Wide Input Voltage Range: 15 to 50 Volts per MIL-STD-704
- Up to 40 Watts Output Power
- Radiation Immune Magnetic Feedback Circuit
- NO Use of Optoisolators
- Undervoltage Lockout
- Indefinite Short Circuit Protection
- Current Limit Protection
- High Input Transient Voltage: 80 Volts for 1 sec per MIL-STD-704A
- Precision Seam Welded Hermetic Package
- High Power Density: > 40 W/in³
- Custom Modified Versions May Be Available
- Additional Environmental Screening Available
- Meets MIL-STD-461C and MIL-STD-461D EMC Requirements When Used With a DVMC28 EMI Filter
- Flanged and Non-flanged Versions Available.
- MIL-PRF-38534 Element Evaluated Components Utilized
- Characterized and assured to 30krads(Si), per VPT's RHA plan specified per MIL-PRF-38534, Appendix G, Level P with 2X margin. After radiation exposure, converter testing is performed at 25°C per standard datasheet limits.
- Characterized to 44 MeV-cm²/mg with minor transients only; no dropouts, shutdowns, latch up or burn out.
- Critical semiconductor component piece-parts and assured converter products tested at an HDR of 80 rads(Si)/sec and an LDR of 8 mrads(Si)/sec.

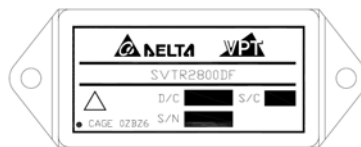


Figure 1 – SVTR2800D / SVTR2800DF DC-DC Converter (Exact marking may differ from that shown)

SPECIFICATIONS ($T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = +28\text{V} \pm 5\%$, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS

Input Voltage (Continuous)	50 V _{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}\text{C}$)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(49 / 52) Grams

Parameter	Conditions	SVTR2805D			SVTR2812D			Units	
		Min	Typ	Max	Min	Typ	Max		
STATIC									
INPUT Voltage ⁴	Continuous	15	28	50	15	28	50	V	
	Transient, 1 sec	-	-	80	-	-	80	V	
Current	Inhibited	-	-	6	-	-	6	mA	
	No Load	-	-	90	-	-	90	mA	
Ripple Current	Full Load ⁵ , 20Hz to 10MHz	-	-	50	-	-	50	mA _{p-p}	
Inhibit Pin Input ⁴		0	-	1.5	0	-	1.5	V	
Inhibit Pin Open Circuit Voltage ⁴		9.0	11.0	13.0	9.0	11.0	13.0	V	
UVLO Turn On		12.0	-	14.8	12.0	-	14.8	V	
UVLO Turn Off ⁴		11.0	-	14.5	11.0	-	14.5	V	
OUTPUT Voltage ⁵	+V _{OUT}	$T_{CASE} = 25^{\circ}\text{C}$	4.95	5.0	5.05	11.88	12.0	12.12	V
	+V _{OUT}	$T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	4.925	5.0	5.075	11.82	12.0	12.18	V
	-V _{OUT}	$T_{CASE} = 25^{\circ}\text{C}$	4.80	5.0	5.20	11.80	12.0	12.20	V
	-V _{OUT}	$T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	4.70	5.0	5.30	11.64	12.0	12.36	V
Power ^{3,6}	Total		0	-	30	0	-	40	W
	$\pm V_{OUT}$	Either Output	0	-	21	0	-	28	W
Current ^{3,6}	$\pm V_{OUT}$	Either Output	0	-	4.2	0	-	2.33	A
Ripple Voltage	$\pm V_{OUT}$	Full Load ⁵ , 20Hz to 10MHz	-	-	60	-	-	50	mV _{p-p}
Line Regulation	+V _{OUT}	$V_{IN} = 16\text{V}$ to 40V	-	-	20	-	-	20	mV
	-V _{OUT}	$V_{IN} = 16\text{V}$ to 40V	-	-	200	-	-	200	mV
Load Regulation	+V _{OUT}	No Load to Full Load ⁵	-	-	50	-	-	50	mV
	-V _{OUT}	No Load to Full Load ^{5,7}	-	-	200	-	-	200	mV
Cross Regulation	-V _{OUT}	+Load 70%, -Load 30% +Load 30%, -Load 70%	-	-	650	-	-	650	mV
EFFICIENCY		Full Load ⁵	73	-	-	78	-	-	%
LOAD FAULT POWER DISSIPATION		Overload ⁴	-	-	16	-	-	14	W
		Short Circuit	-	-	16	-	-	14	W
CAPACITIVE LOAD ⁴		Either Output	-	-	500	-	-	500	μF
SWITCHING FREQUENCY			400	450	550	400	450	550	kHz
SYNC FREQUENCY RANGE		$V_H - V_L = 5\text{V}$, DC = 20-80%	500	-	600	500	-	600	kHz
ISOLATION		500 V _{DC} , $T_{CASE} = 25^{\circ}\text{C}$	100	-	-	100	-	-	M Ω
MTBF (MIL-HDBK-217F)		SF @ $T_C = 55^{\circ}\text{C}$	-	752	-	-	752	-	kHrs

See notes next page.

SPECIFICATIONS ($T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = +28\text{V} \pm 5\%$, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS

Input Voltage (Continuous)	50 V _{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}\text{C}$)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(49 / 52) Grams

Parameter	Conditions	SVTR2805D			SVTR2812D			Units	
		Min	Typ	Max	Min	Typ	Max		
DYNAMIC									
Load Step Output Transient	$\pm V_{OUT}$	Half Load to Full Load	-	-	400	-	-	450	mV _{PK}
Load Step Recovery ²			-	-	350	-	-	400	μSec
Line Step Output Transient ⁴	$\pm V_{OUT}$	$V_{IN} = 16\text{V}$ to 40V	-	300	600	-	500	900	mV _{PK}
Line Step Recovery ^{2,4}			-	300	500	-	300	500	μSec
Turn On Delay	$\pm V_{OUT}$	$V_{IN} = 0\text{V}$ to 28V	-	-	20	-	-	20	mSec
Turn On Overshoot			-	-	25	-	-	50	mV _{PK}

- Notes:
1. Dependant on output voltage.
 2. Time for output voltage to settle within 1% of its nominal value.
 3. Derate linearly to 0 at 135°C.
 4. Verified by qualification testing.
 5. Half load at $+V_{OUT}$ and half load at $-V_{OUT}$.
 6. Up to 70% of the total power or current can be drawn from any one of the two outputs.
 7. 5% Load to Full Load at -55°C.

SPECIFICATIONS ($T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = +28\text{V} \pm 5\%$, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS

Input Voltage (Continuous)	50 V _{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}\text{C}$)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(49 / 52) Grams

Parameter	Conditions	SVTR2815D			Units
		Min	Typ	Max	
STATIC					
INPUT Voltage ⁴	Continuous	15	28	50	V
	Transient, 1 sec	-	-	80	V
Current	Inhibited	-	-	6	mA
	No Load	-	-	90	mA
Ripple Current	Full Load ⁵ , 20Hz to 10MHz	-	-	50	mA _{p-p}
Inhibit Pin Input ⁴		0	-	1.5	V
Inhibit Pin Open Circuit Voltage ⁴		9.0	11.0	13.0	V
UVLO Turn On		12.0	-	14.8	V
UVLO Turn Off ⁴		11.0	-	14.5	V
OUTPUT Voltage ⁵	+V _{OUT} $T_{CASE} = 25^{\circ}\text{C}$	14.85	15.0	15.15	V
	+V _{OUT} $T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	14.70	15.0	15.30	V
	-V _{OUT} $T_{CASE} = 25^{\circ}\text{C}$	14.70	15.0	15.30	V
	-V _{OUT} $T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	14.55	15.0	15.45	V
Power ^{3,6}	Total	-	-	40	W
	$\pm V_{OUT}$ Either Output	-	-	28	W
Current ^{3,6}	$\pm V_{OUT}$ Either Output	-	-	1.87	A
Ripple Voltage	$\pm V_{OUT}$ Full Load ⁵ , 20Hz to 10MHz	-	-	50	mV _{p-p}
Line Regulation	+V _{OUT} $V_{IN} = 16\text{V}$ to 40V	-	-	20	mV
	-V _{OUT} $V_{IN} = 16\text{V}$ to 40V	-	-	200	mV
Load Regulation	+V _{OUT} No Load to Full Load ⁵	-	-	50	mV
	-V _{OUT} No Load to Full Load ^{5,7}	-	-	200	mV
Cross Regulation	-V _{OUT} +Load 70%, -Load 30% +Load 30%, -Load 70%	-	-	650	mV
EFFICIENCY	Full Load ⁵	79	-	-	%
LOAD FAULT POWER DISSIPATION	Overload ⁴	-	-	14	W
	Short Circuit	-	-	14	W
CAPACITIVE LOAD ⁴	Either Output	-	-	500	μF
SWITCHING FREQUENCY		400	450	550	kHz
SYNC FREQUENCY RANGE	$V_H - V_L = 5\text{V}$, DC = 20-80%	500	-	600	kHz
ISOLATION	500 V _{DC} , $T_{CASE} = 25^{\circ}\text{C}$	100	-	-	M Ω
MTBF (MIL-HDBK-217F)	SF @ $T_C = 55^{\circ}\text{C}$	-	752	-	kHrs

See notes next page.

SPECIFICATIONS ($T_{CASE} = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = +28\text{V} \pm 5\%$, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS

Input Voltage (Continuous)	50 V _{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}\text{C}$)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(49 / 52) Grams

Parameter	Conditions	SVTR2815D			Units	
		Min	Typ	Max		
DYNAMIC						
Load Step Output Transient	$\pm V_{OUT}$	Half Load to Full Load	-	-	500	mV _{PK}
Load Step Recovery ²			-	-	300	μSec
Line Step Output Transient ⁴	$\pm V_{OUT}$	$V_{IN} = 16\text{V}$ to 40V	-	500	900	mV _{PK}
Line Step Recovery ^{2,4}			-	300	500	μSec
Turn On Delay	$\pm V_{OUT}$	$V_{IN} = 0\text{V}$ to 28V	-	-	20	mSec
Turn On Overshoot			-	-	50	mV _{PK}

- Notes:
1. Dependant on output voltage.
 2. Time for output voltage to settle within 1% of its nominal value.
 3. Derate linearly to 0 at 135°C.
 4. Verified by qualification testing.
 5. Half load at $+V_{OUT}$ and half load at $-V_{OUT}$.
 6. Up to 70% of the total power or current can be drawn from any one of the two outputs.
 7. 5% Load to Full Load at -55°C.

BLOCK DIAGRAM

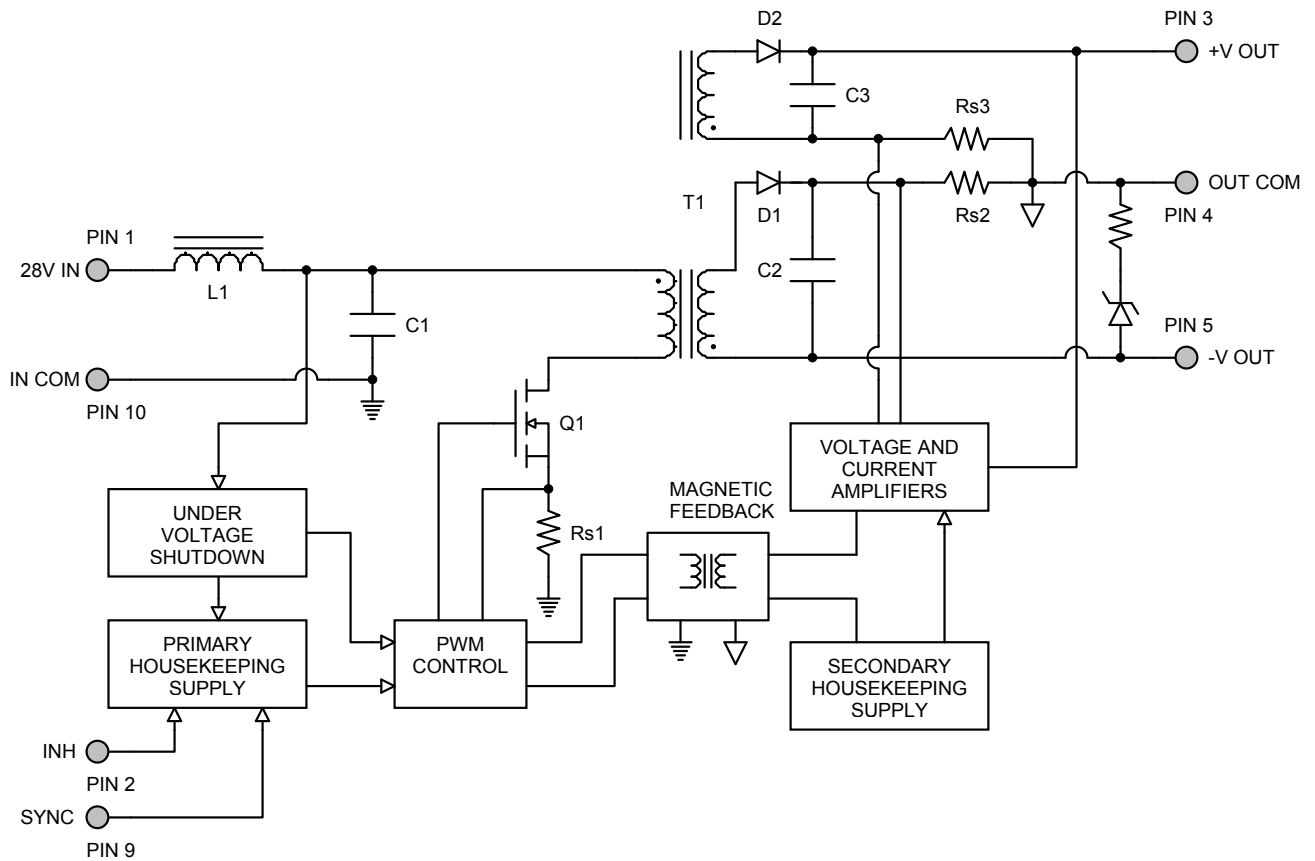


Figure 2

CONNECTION DIAGRAM

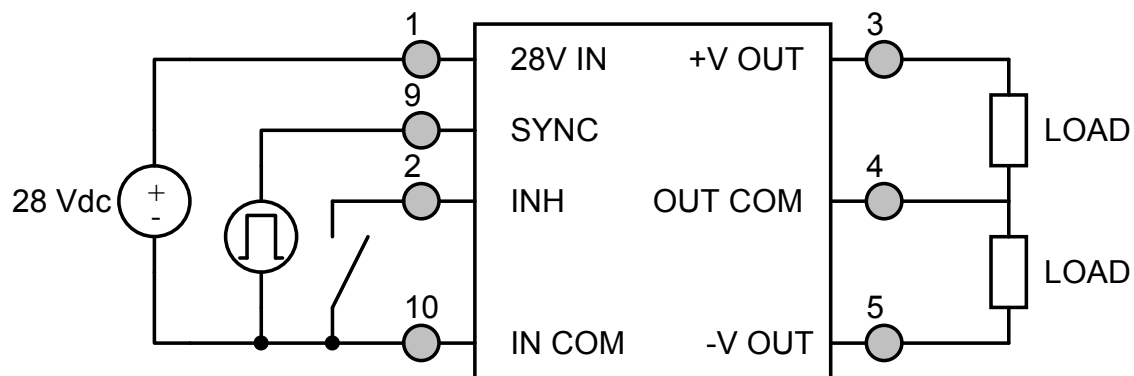


Figure 3

INHIBIT DRIVE CONNECTION DIAGRAMS

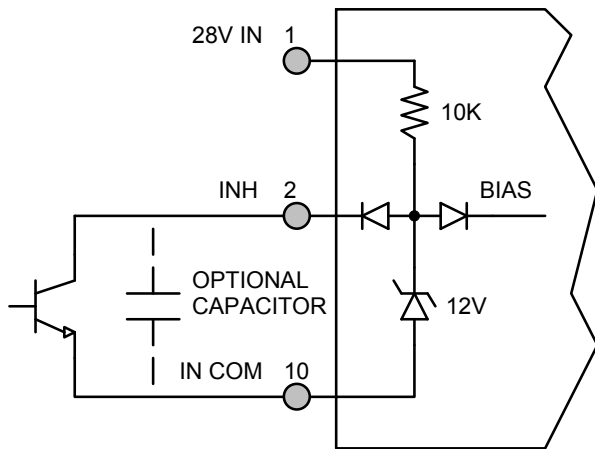


Figure 4 – Internal Inhibit Circuit and Recommended Drive
(Shown with optional capacitor for turn-on delay)

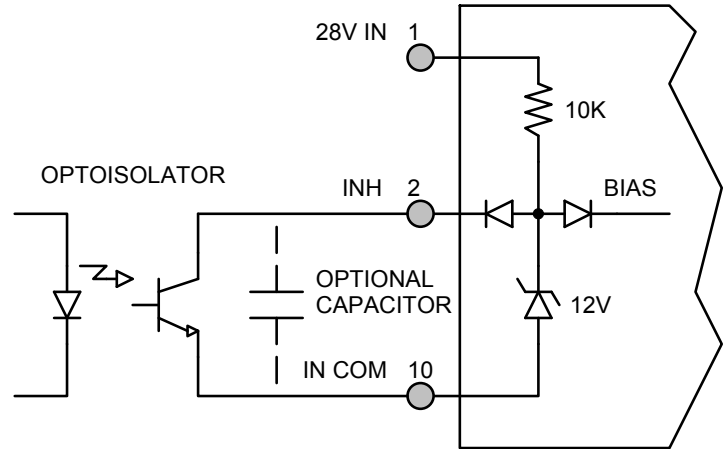


Figure 5 – Isolated Inhibit Drive
(Shown with optional capacitor for turn-on delay)

EMI FILTER HOOKUP DIAGRAM

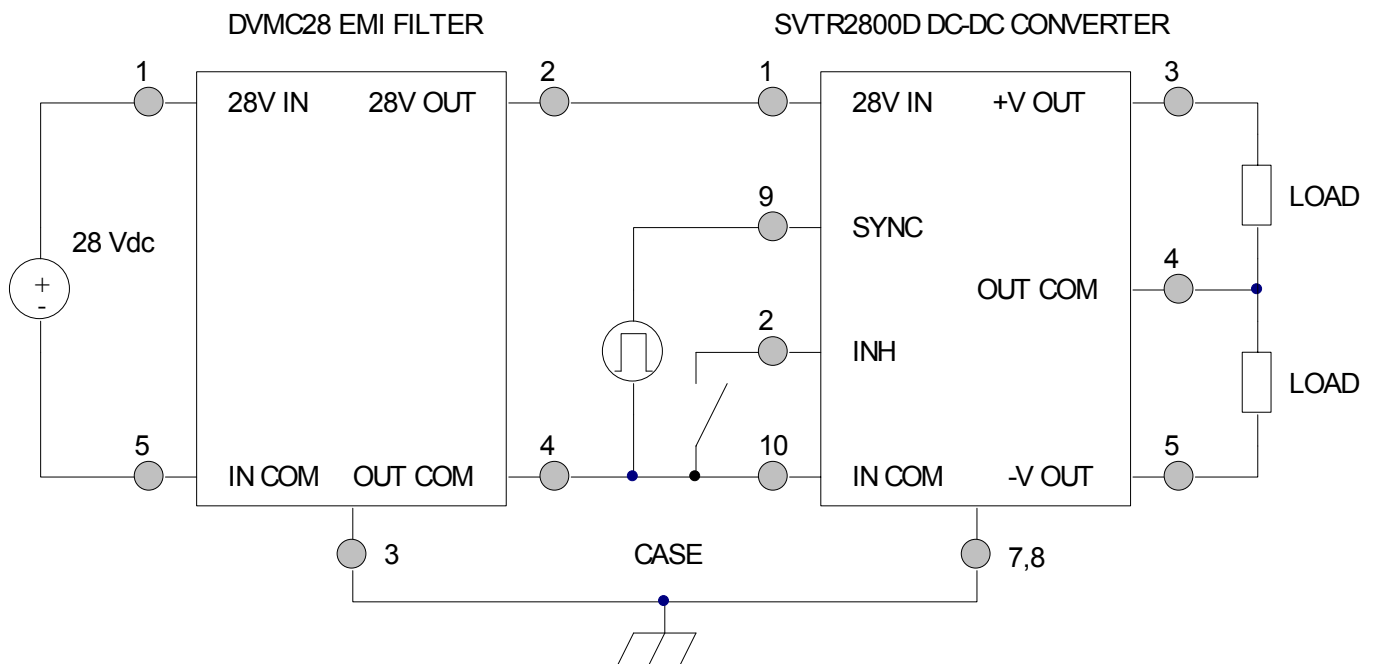


Figure 6 – Converter with EMI Filter

RHA TEST CIRCUIT DIAGRAM

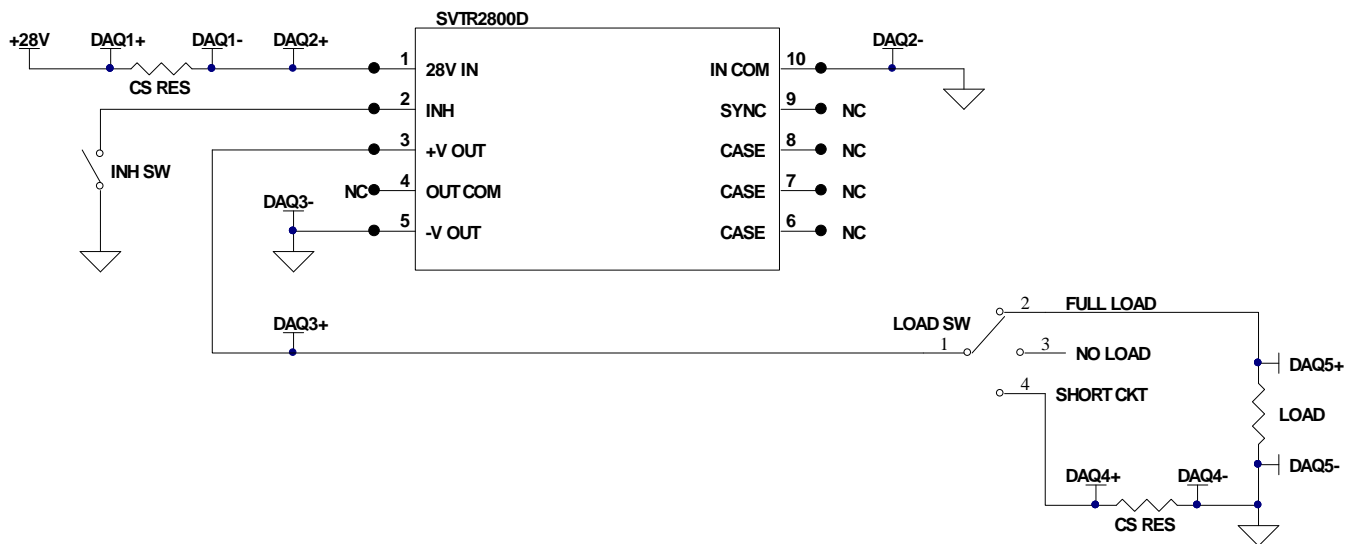


Figure 7

FREQUENCY OF RHA TESTING

Every initial wafer lot of critical semiconductor components has been characterized and tested at HDR as well as at LDR to determine if there is ELDRS sensitivity. If a specific component type is determined to have ELDRS sensitivity, all future wafer lots of that specific component will be tested at LDR. If no ELDRS sensitivity is shown in the initial wafer lot testing, future wafer lots of those specific components will not be tested at LDR. All future critical semiconductor component wafer lots are tested at HDR. If the components test to the same level (within 15% of the previous 99/90 RLAT level) or better as the wafer lot used to characterize the converter family, the converter family is not re-characterized. If the components test to a worse level, one of the following actions is performed (depending on the test level passed):

1. Component lot is not used in VPT RHA assured product.
2. Component lot is used if WCA (Worst Case Analysis) performed on the new lot against the original characterization WCA determines the component level characterized will not negatively impact the assured product characterization level.
3. The assured product is re-characterized using the new component lot.

EFFICIENCY PERFORMANCE CURVES ($T_{CASE} = 25^{\circ}C$, Full Load, Unless Otherwise Specified)

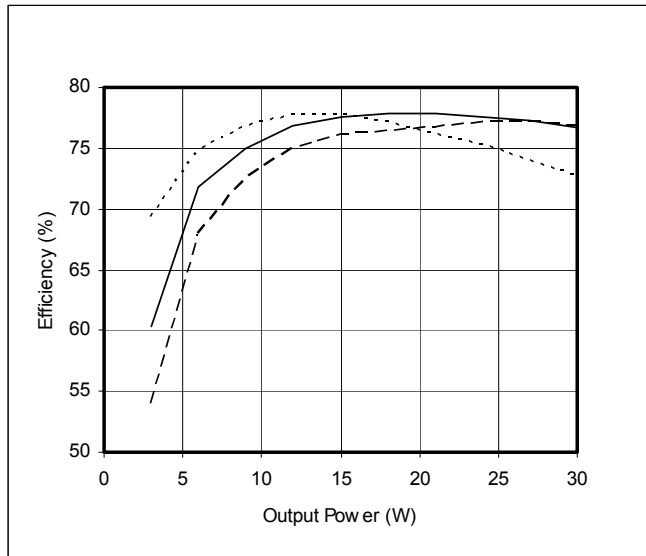
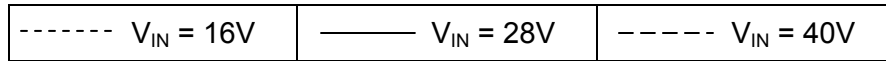


Figure 8 – SVTR2805D

Efficiency (%) vs. Output Power (W)

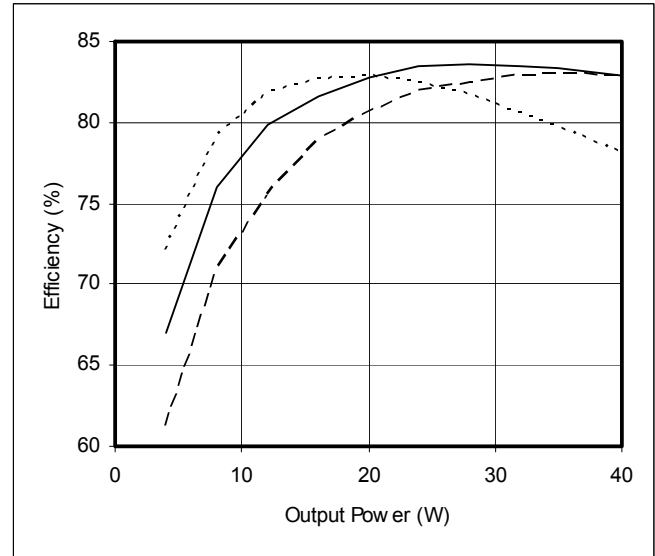


Figure 9 – SVTR2812D

Efficiency (%) vs. Output Power (W)

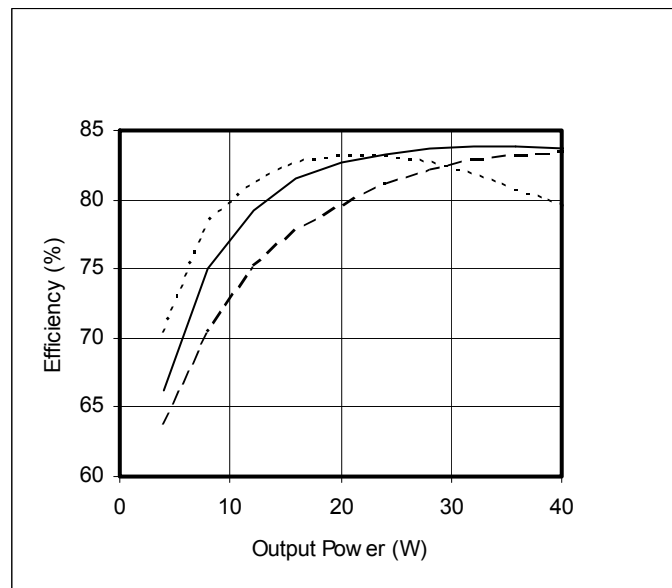


Figure 10 – SVTR2815D

Efficiency (%) vs. Output Power (W)

EMI PERFORMANCE CURVES

($T_{CASE} = 25^{\circ}C$, $V_{IN} = +28V \pm 5\%$, Full Load, Unless Otherwise Specified)

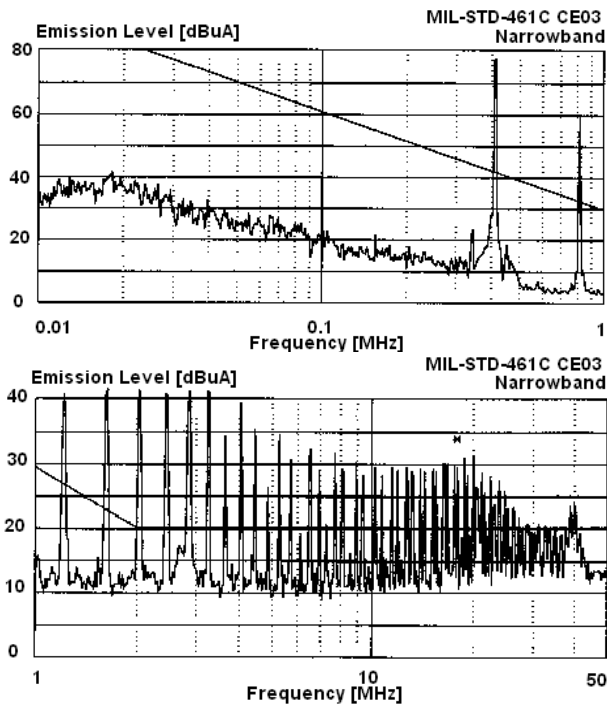


Figure 11 – SVTR2800D without EMI Filter

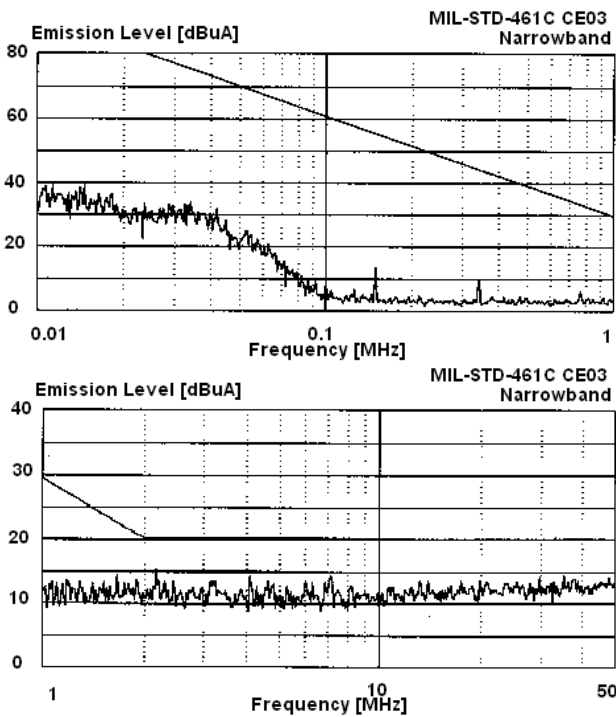
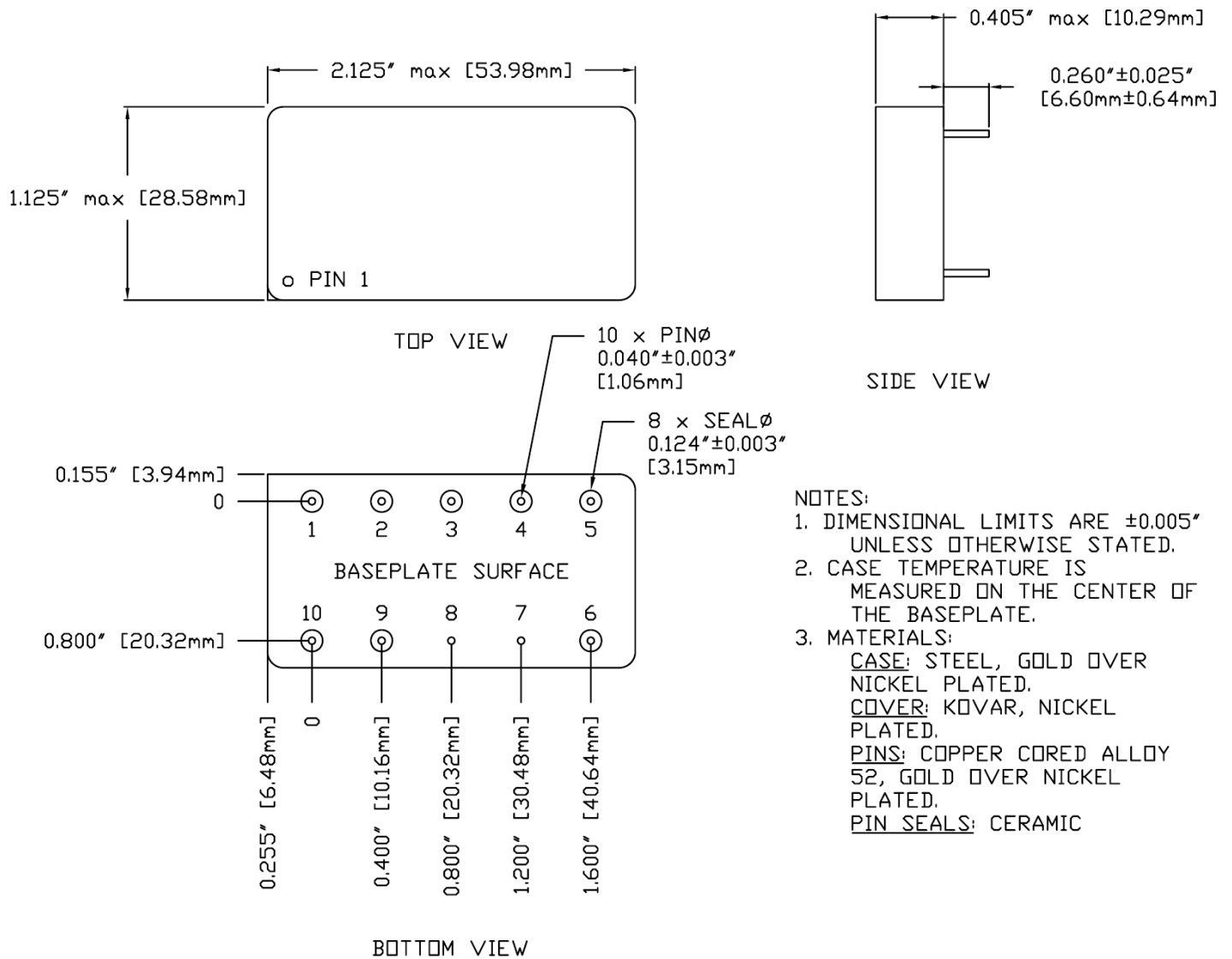


Figure 12 – SVTR2800D with EMI Filter

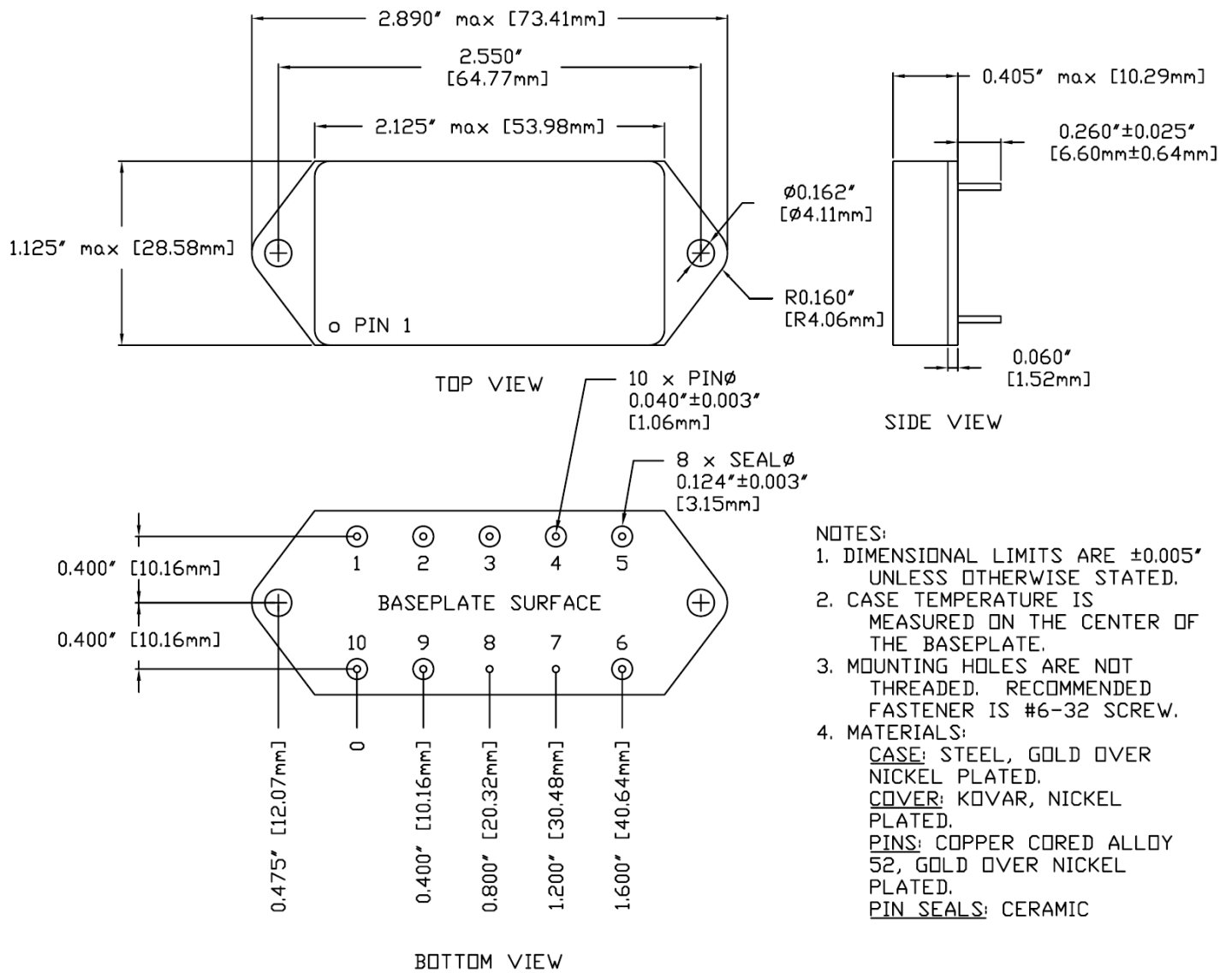
PACKAGE SPECIFICATIONS (NON-FLANGED)



PIN	FUNCTION	PIN	FUNCTION
1	28V IN	6	CASE
2	INHIBIT	7	CASE
3	+V OUT	8	CASE
4	OUT COM	9	SYNC
5	-V OUT	10	IN COM

Figure 13 – Non-Flanged Package and Pinout

PACKAGE SPECIFICATIONS (FLANGED)



PIN	FUNCTION	PIN	FUNCTION
1	28V IN	6	CASE
2	INHIBIT	7	CASE
3	+V OUT	8	CASE
4	OUT COM	9	SYNC
5	-V OUT	10	IN COM

Figure 14 – Flanged Package and Pinout

PACKAGE PIN DESCRIPTION

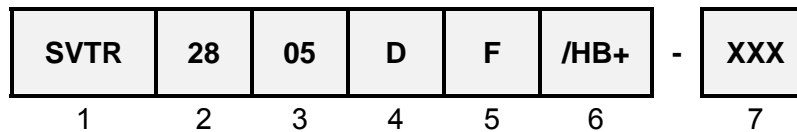
Pin	Function	Description
1	28V IN	Positive Input Voltage Connection
2	INHIBIT	Logic Low = Disabled Output. Connecting the inhibit pin to input common causes converter shutdown. Logic High = Enabled Output. Unconnected or open collector TTL.
3	+V OUT	Positive Output Voltage Connection
4	OUT COM	Output Common Connection
5	-V OUT	Negative Output Voltage Connection
6	CASE	Case Connection
7	CASE	Case Connection
8	CASE	Case Connection
9	SYNC	Synchronization Signal
10	IN COM	Input Common Connection

ENVIRONMENTAL SCREENING (100% Tested Per MIL-STD-883 as referenced to MIL-PRF-38534)

Screening	MIL-STD-883	Class HB+ /HB+	Engineering Model ⁵ /EM
Non-Destructive Bond Pull	Method 2023	•	•
Internal Visual	Method 2017, 2032 Internal Procedure	•	•
Temperature Cycling	Method 1010, Condition C	•	
Constant Acceleration	Method 2001, 3000g, Y1 Direction	•	
PIND	Method 2020, Condition A ²	•	
Burn-In	Method 1015, 160 hours at +125°C 24 Hours at +125°C	•	•
Final Electrical	MIL-PRF-38534, Group A ¹ 100% at 25°C	•	•
Hermeticity	Method 1014, Fine Leak, Condition A Method 1014, Gross Leak, Condition C Dip (1×10^{-3})	• •	•
External Visual	Method 2009	•	•

- Notes:
- 100% R&R testing at -55°C, +25°C, and +125°C with all test data included in product shipment.
 - PIND test Certificate of Compliance included in product shipment.
 - Non-Destructive bond pull per Method 2023 performed.
 - Please contact your sales representative or the VPT Inc. Sales Department for more information concerning additional environmental screening and testing options desired.
 - Engineering models utilize only the standard screening specified and are not considered compliant for flight use.

ORDERING INFORMATION



(1)	(2)		(3)		(4)	
Product Series	Nominal Input Voltage		Output Voltage		Number of Outputs	
SVTR	28	28 Volts	05 12 15	± 5 Volts ± 12 Volts ± 15 Volts	D	Dual

(5)		(6)		(7)
Package Option		Screening Code		Additional Screening Code
None F	Non-Flanged Flanged	/HB+ /EM	HB+ Engineering Model	Contact Sales

Note: Engineering models utilize only the standard screening specified and are not considered compliant for flight use. These models are intended for low volume engineering characterization. The customer must place the following statement on each line item of their purchase order(s) for /EM units when ordering engineering models:

“(Customer Name) acknowledges that the /EM unit listed in this line item is not permitted for flight use and will be used for Engineering characterization only.”

Please contact your sales representative or the VPT Inc. Sales Department for more information concerning additional environmental screening and testing, different input voltage, output voltage, power requirement, source inspection, and/or special element evaluation for space or other higher quality applications.

CONTACT INFORMATION

To request a quotation or place orders please contact your sales representative or the VPT Inc. Sales Department at:

Phone: (425) 353-3010
Fax: (425) 353-4030
E-mail: vptsales@vpt-inc.com

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